

MD1803DFP

High voltage NPN Power transistor for standard definition CRT display

Features

- State-of-the-art technology:
 - Diffused collector "enhanced generation"
- Stable performance versus operating temperature variation
- Low base drive requirement
- Tight h_{FE} range at operating collector current
- Fully insulated power package UL compliant
- Integrated free wheeling diode

Applications

■ Horizontal deflection output for TV

Description

The MD1803DFP is manufactured using diffused collector in planar technology adopting new and enhanced high voltage structure. The new MD product series show improved silicon efficiency bringing updated performance to the horizontal deflection stage.

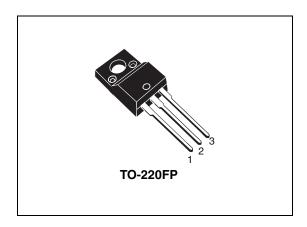


Figure 1. Internal schematic diagram

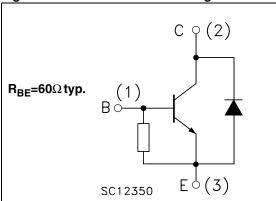


Table 1. Device summary

Order code	Marking	Package	Packing	
MD1803DFP	MD1803DFP	TO-220FP	Tube	

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Electrical ratings MD1803DFP

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	700	V
V _{EBO}	Emitter-base voltage (I _C = 0)	10	V
I _C	Collector current	10	Α
I _{CM}	Collector peak current (t _P < 5ms)	15	Α
I _B	Base current	5	Α
P _{TOT}	Total dissipation at T _c = 25°C	40	W
V _{isol}	Insulation withstand voltage (rms) from all three leads to external heatsink	1500	V
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	3.125	°C/W

MD1803DFP Electrical characteristics

2 Electrical characteristics

(T_{CASE} = 25°C; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1500 V V _{CE} = 1500 V	T _c = 125 °C			0.2 2	mA mA
I _{EBO}	Emitter cut-off current $(I_C = 0)$	V _{EB} = 5 V		40		120	mA
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	I _E = 700 mA		10			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 5 A	I _B = 1.25 A			2	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 5 A	I _B = 1.25 A			1.2	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 1 A$ $I_C = 5 A$ $I_C = 5 A$	$V_{CE} = 5 V$ $V_{CE} = 1 V$ $V_{CE} = 5 V$	5.5	18 5	7.5	
V_{F}	Diode forward voltage	I _F = 5 A				1.6	V
t _s	Inductive load Storage time Fall time	$I_{B(on)} = 0.6 A$	$f_h = 16 \text{ KHz}$ $V_{BE(off)} = -2.7V$		2.5 0.3	3 0.6	μs
чf	i ali liille	$L_{BB(off)} = 4.5 \mu H$	I		0.5	0.0	μs

^{1.} Pulsed duration = 300 ms, duty cycle \leq 1.5%.

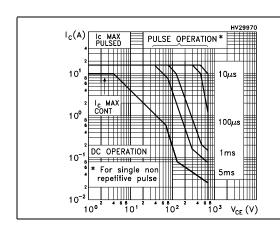
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Electrical characteristics MD1803DFP

2.1 Electrical characteristics (curve)

Figure 2. Safe operating area

Figure 3. Derating curve



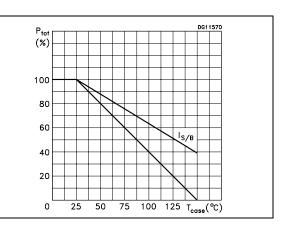
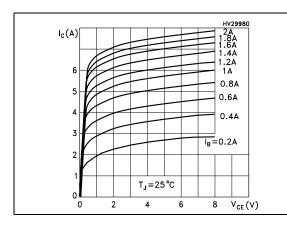
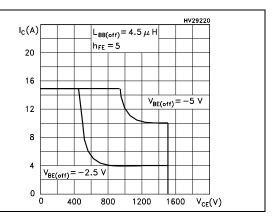


Figure 4. Output characteristics

Figure 5. Reverse biased SOA





MD1803DFP Electrical characteristics

Figure 6. DC current gain

Figure 7. DC current gain

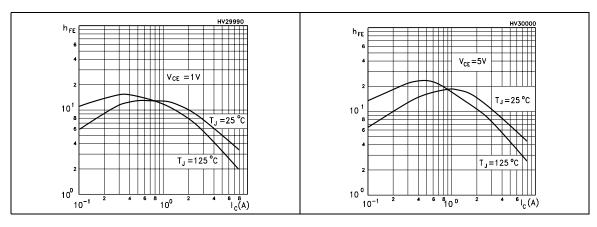


Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage

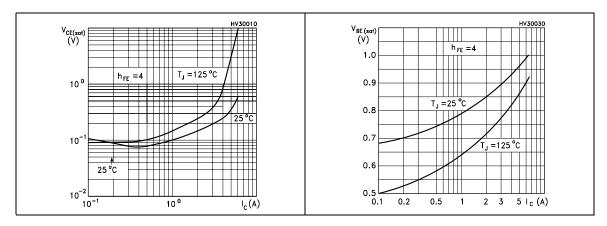
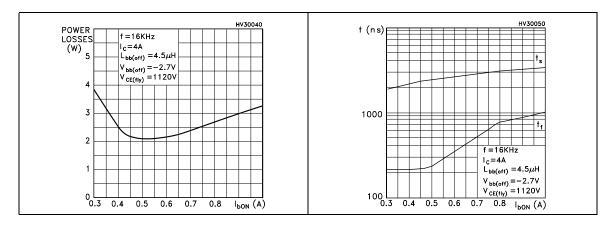


Figure 10. Power losses

Figure 11. Inductive load switching time



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Test circuit MD1803DFP

3 Test circuit

Figure 12. Power losses and inductive load switching test circuit

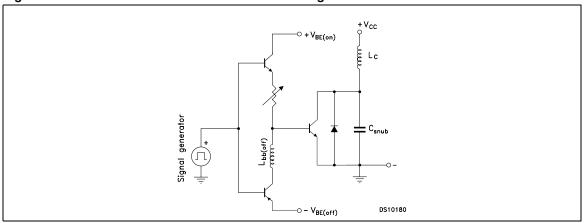
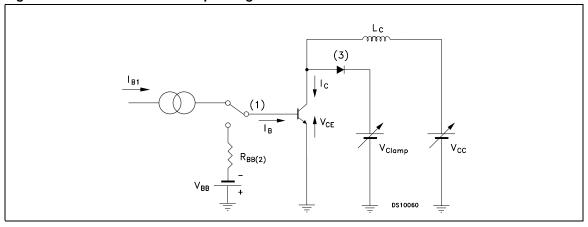


Figure 13. Reverse biased safe operating area test circuit



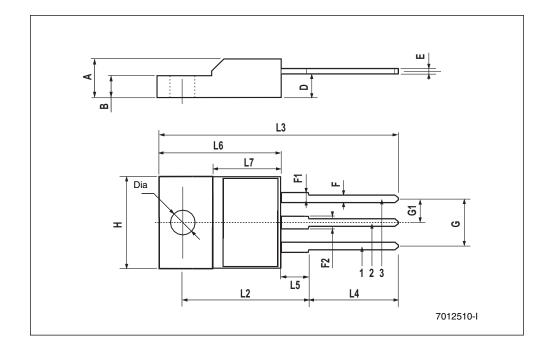
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



TO-220FP	mechanical	data
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Dim.		mm.			inch	
Dilli.	Min.	Тур	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
В	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
E	0.45		0.70	0.017		0.027
F	0.75		1.00	0.030		0.039
F1	1.15		1.50	0.045		0.067
F2	1.15		1.50	0.045		0.067
G	4.95		5.20	0.195		0.204
G1	2.40		2.70	0.094		0.106
Н	10		10.40	0.393		0.409
L2		16			0.630	
L3	28.6		30.6	1.126		1.204
L4	9.80		10.60	0.385		0.417
L5	2.9		3.6	0.114		0.141
L6	15.90		16.40	0.626		0.645
L7	9		9.30	0.354		0.366
Dia	3		3.2	0.118		0.126



MD1803DFP Revision history

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
27-May-2008	1	First release

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